

# MN61113, MN61113S

## 2K-Bit EEPROMs

### ■ Overview

The MN61113 and MN61113S are 2048-bit, bit sequential EEPROMs with built-in address counters. They sequentially increment the address with the clock input to produce serial output.

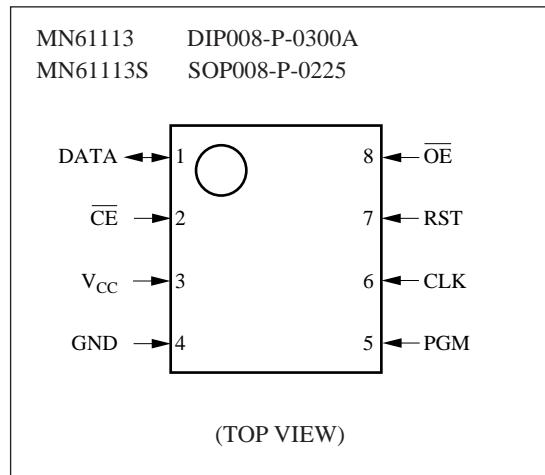
They include built-in charge pump circuit and timer for automatically erasing, writing, and modifying data using only a single 3 volt power supply.

To reduce write times, they include a block write function for writing up to 32 bits at a time. This function makes it possible to rewrite the contents of all 2048 bits within 1 second (typ.).

### ■ Features

- 2048 words × 1 bit organization
  - Built-in reset function
  - Tristate output
  - Low power consumption
    - 3 volt read: 1.5 mW (max.)
    - 3 volt program: 6 mW (max.)
    - 3 volt standby: 60 µW (max.)
  - Single 3 volt power supply (charge pump circuit built in)
  - Self timer for use in automatically erasing and writing data
  - Built-in data polling function
  - Write cycles:  $10^5$  times
  - Data storage interval: 10 years
  - Pull-up resistor on  $\overline{CE}$  pin.
- Pull-down resistors on PGM, CLK, and RST pins

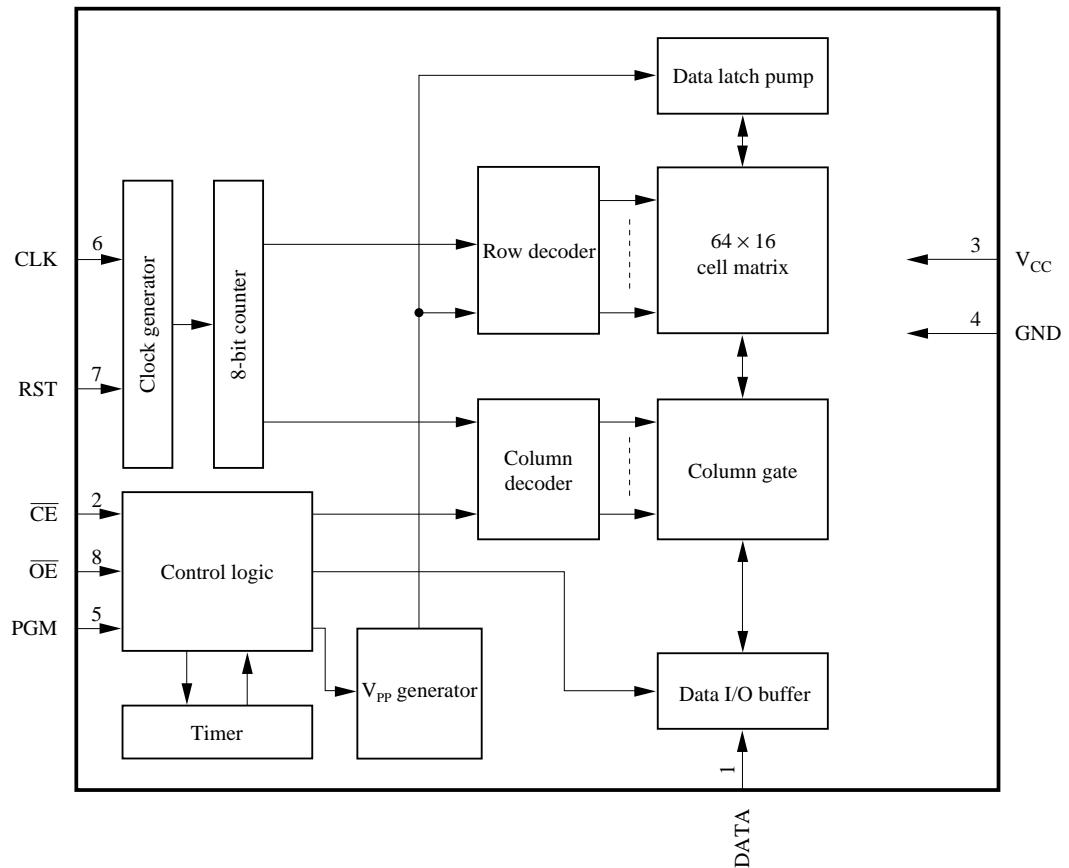
### ■ Pin Assignment



### ■ Applications

- Personal wireless equipment, cordless telephones, storage for recognition and adjustment data for terminals, etc.

## ■ Block Diagram



### ■ Pin Descriptions

Pin No.	Symbol	Pin Name
1	DATA	Data I/O
2	$\overline{CE}$	Chip enable
3	$V_{CC}$	Power supply voltage
4	GND	Ground
5	PGM	Program
6	CLK	Clock input
7	RST	Reset input
8	$\overline{OE}$	Output enable

### ■ Electrical Characteristics

$V_{CC}=2.6$  to  $3.5V$ ,  $T_a=-10^{\circ}C$  to  $+60^{\circ}C$

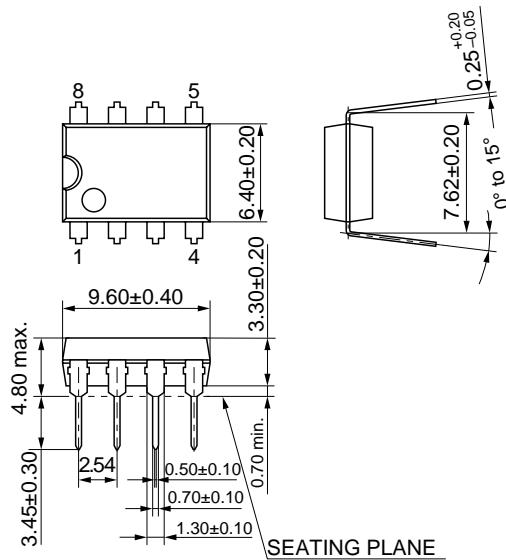
Parameter	Symbol	Test Conditions	3 Volt Operation		Unit
			min	max	
Power supply voltage	$V_{CC}$	Read mode	2.6	3.5	V
		Program mode	3.0	3.5	
"L" level input leakage current	$I_{LIL}$	$\overline{CE}$ pin	-50	—	$\mu A$
		Other pins	-10	10	
"H" level input leakage current	$I_{LIH}$	PGM, CLK, and RST pins	—	-20	$\mu A$
		Other pins	-10	10	
Output leakage current	$I_{LO}$		—	10	$\mu A$
"L" level input voltage	$V_{IL}$		-0.1	0.2 $V_{CC}$	V
"H" level input voltage	$V_{IH}$		0.8 $V_{CC}$	$V_{CC}$ +0.3	V
$V_{CC}$ power supply current (during operation)	$I_{CC}$	Read mode CLK;f=250kHz	—	500	$\mu A$
		Program mode	—	2000	
$V_{CC}$ power supply current (during standby)	$I_{SB}$	$\overline{CE} = V_{CC} + 0.3 V$ ; RST and PGM pins at $V_{CC}$ ; CLK pin open	—	20	$\mu A$
"L" level output voltage	$V_{OL}$	$I_{OL}=400\mu A$	—	0.3	V
"H" level output voltage	$V_{OH}$	$I_{OH}=10\mu A$	$V_{CC}$ -0.3	—	V

**■ Function Descriptions****Operating Modes**

Pin Symbol (Pin No.)	$\overline{CE}$ (2)	$\overline{OE}$ (8)	PGM (5)	DATA (1)
Operating Mode				
Read	$V_{IL}$	$V_{IL}$	×	$D_{OUT}$
Standby	$V_{IH}$	×	×	High-impedance
Program	$V_{IL}$	$V_{IH}$	$\square\!\!\!/_\!$	$D_{IN}$

## ■ Package Dimensions (Unit:mm)

- MN61113 DIP008-P-0300A



- MN61113S SOP008-P-0225

